2/24/04

FORM PTO-1449 (MODIFIED)						ATTY DOCKET NO.			SERIAL NO. 10/789,527			
LIST OF PATENTS AND PUBLICATIONS						67,200-1247			10/703,097			
FOR APPLICANT'S INFORMATION						Applicant: Kuo-Chi Tu						
DISCLOSURE STATEMENT						FILING DATE			GROUP -Unknown-			
(Use several sheets if necessary) REFERENCE DESIGNATION U.S. PATENT DOCUME						Filed Herewith 2822						
EXAMINER	DESIGN	ATION U.S. PA	JMEI	NTS .				SUB	FILING			
INITIAL		NO.		DATE		NAME		CLASS		CLASS	1 1	
MP	AA	5,360,753		11/1994		Park et al			_			
MP	AB	5,696,021		12/1997		Chan et al			_			
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MP	ΑĎ	6,232,202B1		05/2001		Hong			_		-	
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MP	Αl	6,573,548B2		06/2003		Leung et al			<u>٠</u>		-	
	AJ									-		
FOREIGN PATENT DOCUMENTS												
EXAMINER INITIAL		DOCUMENT NO.		DATE		COUNTRY		LASS	SUB CLASS		TRANSLATION YES/NO	
	AK											
	AL											
	АМ											
	AN											
OTHER ART (including Author, Title, Date, pertinent pages, etc.)												
MP	AO	"A 130 nm Generation High Density Etox™ Flash Memory Technology", Kenney, IEEE, IEDM 2001, pp. 41-44, December 2001										
	AP AP											
EXAMINER	DATE CONSIDERED 6/05											
	EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and											